TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4051AP, TC74HC4051AF, TC74HC4051AFT TC74HC4052AP, TC74HC4052AF, TC74HC4052AFT TC74HC4053AP, TC74HC4053AF, TC74HC4053AFT

TC74HC4051AP/AF/AFT

8-Channel Analog

Multiplexer/Demultiplexer

TC74HC4052AP/AF/AFT

Dual 4-Channel Analog Multiplexer/Demultiplexer

TC74HC4053AP/AF/AFT

Triple 2-Channel Analog Multiplexer/Demultiplexer

The TC74HC4051A/4052A/4053A are high speed CMOS ANALOG MULTIPLEXER/DEMULTIPLEXER fabricated with silicon gate C²MOS technology. They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC4051A has an 8 channel configuration, the TC74HC4052A has a 4 channel \times 2 configuration and the TC74HC4053A has a 2 channel \times 3 configuration.

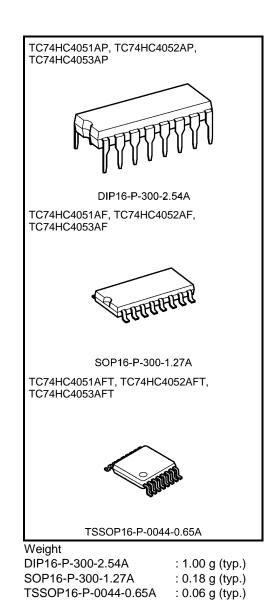
The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal ($V_{CC} - V_{EE}$) can then be switched by the small logical amplitude ($V_{CC} - GND$) control signal.

For example, in the case of $V_{CC} = 5 V$, GND = 0 V, $V_{EE} = -5 V$, signals between -5 V and +5 V can be switched from the logical circuit with a single power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuits with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

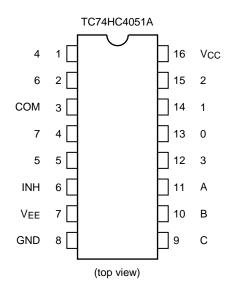
Features

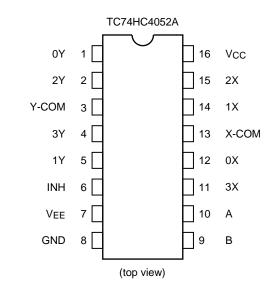
- High speed: t_{pd} = 15 ns (typ.) at VCC = 5 V, VEE = 0 V
- Low power dissipation: $I_{CC} = 4 \mu A \pmod{at Ta} = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Low ON resistance: $RON = 50 \Omega$ (typ.) at VCC VEE = 9 V
- High noise immunity: THD = 0.02% (typ.) at V_{CC} V_{EE} = 9 V
- Pin and function compatible with 4051/4052/4053B

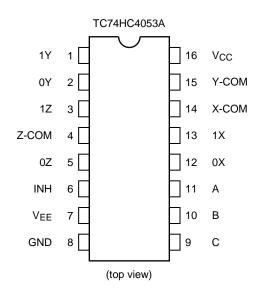


Start of commercial production 1986-05

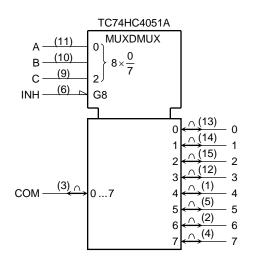
Pin Assignment

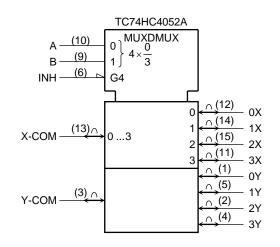


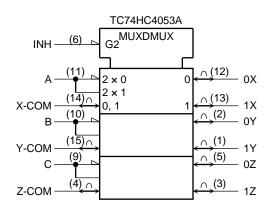




IEC Logic Symbol







Truth Table

	Contro	I Inputs		"ON" Channel				
Inhibit	C*	В	А	HC4051A	HC4052A	HC4053A		
L	L	L	L	0	0X, 0Y	0X, 0Y, 0Z		
L	L	L	Н	1	1X, 1Y	1X, 0Y, 0Z		
L	L	Н	L	2	2X, 2Y	0X, 1Y, 0Z		
L	L	Н	Н	3	3X, 3Y	1X, 1Y, 0Z		
L	Н	L	L	4	_	0X, 0Y, 1Z		
L	Н	L	Н	5	—	1X, 0Y, 1Z		
L	Н	Н	L	6	_	0X, 1Y, 1Z		
L	Н	Н	Н	7	—	1X, 1Y, 1Z		
Н	Х	Х	Х	None	None	None		

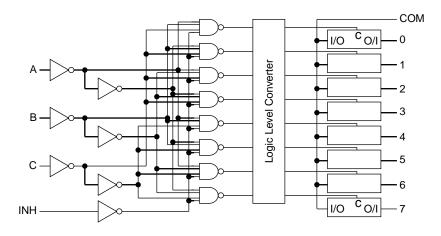
X: Don't care

*: Except HC4052A

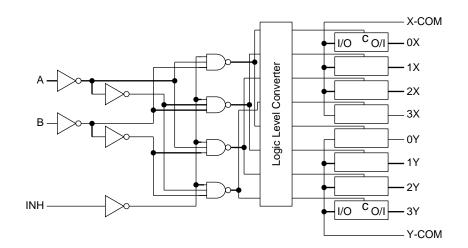


System Diagram

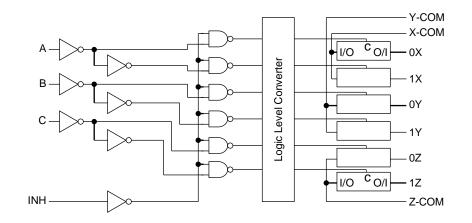
TC74HC4051A



TC74HC4052A



TC74HC4053A



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5 to 7	V
Supply voltage range	VCC-VEE	-0.5 to 13	V
Control input voltage	VIN	-0.5 to V _{CC} + 0.5	V
Switch I/O voltage	VI/O	VEE - 0.5 to VCC + 0.5	V
Control input diode current	ICK	±20	mA
I/O diode current	liok	±20	mA
Switch through current	Ι _Τ	±25	mA
DC V_{CC} or ground current	ICC	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	2 to 6	V
Supply voltage range	VEE	-6 to 0	V
Supply voltage range	VCC-VEE	2 to 12	V
Control input voltage	Vin	0 to Vcc	V
Switch I/O voltage	VI/O	VEE to VCC	V
Operating temperature	Topr	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Control input rise and fall time	tr, tf	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Operating Ranges (Note)

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
Characteriolice	Cymbol	VEE (V		V _{CC} (V)	Min	Тур.	Max	Min	Max	onit
				2.0	1.50	_	_	1.50	_	V
High-level control input voltage	VIHC	—		4.5	3.15	—	—	3.15	—	
5				6.0	4.20	—		4.20	—	
				2.0	—	—	0.50	—	0.50	
Low-level control input voltage	VILC	_		4.5	—	—	1.35	—	1.35	V
				6.0	—	—	1.80	—	1.80	
		$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	GND	4.5	—	85	180	—	225	
		$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5	—	55	120	—	150	Ω
	R _{ON}	$I_{I/O} \leq 2 \ mA$	-6.0	6.0	—	50	100	_	125	
ON resistance		$\label{eq:VIN} \begin{split} V_{IN} &= V_{ILC} \text{ or } V_{IHC} \\ V_{I/O} &= V_{CC} \text{ or } V_{EE} \\ I_{I/O} &\leq 2 \text{ mA} \end{split}$	GND	2.0	—	150	—	—	—	
			GND	4.5	—	70	150	—	190	
			-4.5	4.5	—	50	100	—	125	
			-6.0	6.0	—	45	80	—	100	
Difference of ON	ΔR _{ON}	$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	GND	4.5	—	10	30	—	35	
resistance between switches		$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5	—	5	12	—	15	Ω
Switches		$I_{I/O} \leq 2 \ mA$	-6.0	6.0	—	5	10	—	12	
Input/output leakage		$V_{OS} = V_{CC} \text{ or } GND$	GND	6.0	_	_	±60	_	±600	
current	IOFF	$V_{IS} = GND \text{ or } V_{CC}$	-6.0	6.0	_	_	±100	_	±1000	nA
(switch off)		$V_{IN} = V_{ILC} \text{ or } V_{IHC}$								
Switch input leakage current	Vos	$V_{OS} = V_{CC}$ or GND	GND	6.0	_	_	±60	_	±600	
(switch on, output open)	lız	$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	-6.0	6.0	_	—	±100	—	±1000	nA
Control input current	l _{IN}	$V_{IN} = V_{CC}$ or GND	GND	6.0	_	—	±0.1	_	±1.0	μΑ
	1		GND	6.0	—	_	4.0	_	40.0	٨
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND	-6.0	6.0	_	—	8.0	—	80.0	μA

AC Characteristics (CL = 50 pF, input: tr = tf = 6 ns, GND = 0 V)

Characteristics	Symbol		Test Cor	ndition		-	Га = 25°0)		a = 0 85°C	Unit
Characteristics	Symbol			V _{EE} (V)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
				GND	2.0	_	25	60	_	75	
Phase difference				GND	4.5	_	6	12	_	15	
between input and output	φι/Ο	All types		GND	6.0	_	5	10	_	13	ns
000				-4.5	4.5		4	_	_	_	
				GND	2.0	_	64	225	_	280	
				GND	4.5	_	18	45	_	56	
		4051A	(Note 1)	GND	6.0	_	15	38	_	48	
				-4.5	4.5		18	_	_	_	
				GND	2.0	_	64	225	_	280	
	t _{pZL}			GND	4.5	_	18	45	_	56	
Output enable time	t _{pZH}	4052A	(Note 1)	GND	6.0	_	15	38	_	48	ns
				-4.5	4.5		18	_	_	_	
				GND	2.0	_	50	225	_	280	
			(Note 1)	GND	4.5	_	14	45	_	56	
		4053A		GND	6.0	_	12	38	_	48	
				-4.5	4.5		14	_	_	_	
	t _{PLZ} t _{PHZ}		(Note 1)	GND	2.0	_	100	250	_	315	
		4051A		GND	4.5	_	33	50	_	63	ns
				GND	6.0	_	28	43	_	54	
				-4.5	4.5		29	_	_	_	
		4052A	(Note 1)	GND	2.0	_	100	250	_	315	
				GND	4.5	_	33	50	_	63	
Output disable time				GND	6.0	_	28	43	_	54	
				-4.5	4.5		29	_	_	_	
				GND	2.0	_	95	225	_	280	
				GND	4.5	_	30	45	_	56	
		4053A	(Note 1)	GND	6.0	_	26	38	_	48	
				-4.5	4.5		26	_	_	_	
Control input capacitance	CIN	All types		_	_	_	5	10	_	10	pF
		4051A				_	36	70	_	70	
COMMON terminal capacitance	CIS	4052A		-5.0	5.0	_	19	40	_	40	pF
capacitance		4053A				_	11	20	_	20	
		4051A				_	7	15	_	15	
SWITCH terminal capacitance	Cos	4052A		-5.0	5.0	_	7	15	_	15	pF
capacitarice		4053A				_	7	15	_	15	
		4051A				_	0.95	2	_	2	
Feedthrough capacitance	Cios	4052A		-5.0	5.0	_	0.85	2	_	2	pF
capacitance		4053A				_	0.75	2	_	2	
		4051A	(Note 2)			_	70		_	_	
Power dissipation	Cpd	4052A	(Note 2)	GND	5.0	_	71	_	_	_	pF
capacitance		4053A	(Note 2)			_	67	_	_	_	

Note 1: $RL = 1 k\Omega$

Note 2: CPD is defined as the value of the internal equivalent capacitance of IC which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC$

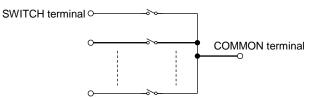
Analog Switch Characteristics (GND = 0 V, Ta = 25°C) (Note 1)

		Test C	Тур.	Unit			
Characteristics	Symbol						
		$R_L = 10 \ k\Omega$,	$V_{IN} = 4.0 V_{p-p}$	-2.25	2.25	0.025	
Sine wave distortion (T.H.D)		C _L = 50 pF	$V_{IN} = 8.0 V_{p-p}$	-4.5	4.5	0.020	%
		f _{IN} = 1 kHz	VIN = 11.0 Vp-p	-6.0	6.0	0.018	
			All (Note 2)			120	
			4051A (Note 3)	-2.25	2.25	45	
			4052A (Note 3)	-2.25	2.25	70	
		Adjust f _{IN} voltage to obtain	4053A (Note 3)			95	MHz
		OdBm at V _{OS}	All (Note 2)	-4.5 -6.0	4.5	190	
Frequency response	fmax	Increase f _{IN} frequency until dB meter reads -3dB $R_L = 50 \Omega$, $C_L = 10 pF$ $f_{IN} = 1 MHz$, sine wave	4051A (Note 3)			70	
(switch on)			4052A (Note 3)			110	
			4053A (Note 3)			150	
			All (Note 2)		6.0	200	
			4051A (Note 3)			85	
			4052A (Note 3)			140	
			4053A (Note 3)			190	
		V_{IN} is centered at (V _{CC} - V _{EE})/2	-2.25	2.25	-50	
Feed through attenuation		Adjust input for 0dBm		-4.5 4.5		-50	dB
(switch off)		$R_L = 600 \Omega, C_L = 50 pF$			6.0	-50	
		f _{IN} = 1 MHz, sine wave					
Crosstalk		$R_{I} = 600 \Omega, C_{I} = 50 pF$		-2.25	2.25	60	
(control input to signal output)		f _{IN} = 1 MHz, square wave	(t _r = t _f = 6 ns)	-4.5 4.5	140	mV	
				-6.0	6.0	200	
Crosstalk		Adjust V_{IN} to obtain 0dBm at	input	-2.25	2.25	-50	
(between any switches)		$R_L = 600 \Omega$, $C_L = 50 pF$	-4.5	4.5	-50	dB	
		f _{IN} = 1 MHz, sine wave		-6.0	6.0	-50	

Note 1: These characteristics are determined by design of devices.

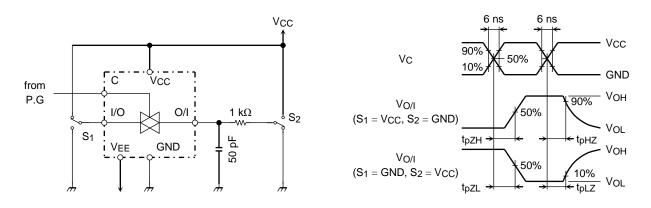
Note 2: Input COMMON terminal, and measured at SWITCH terminal.

Note 3: Input SWITCH terminal, and measured at COMMON terminal.

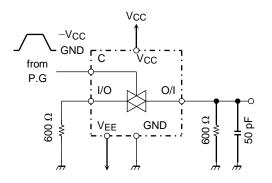


Switching Characteristics Test Circuits

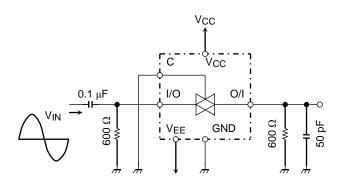
1. tpLZ, tpHZ, tpZL, tpZH



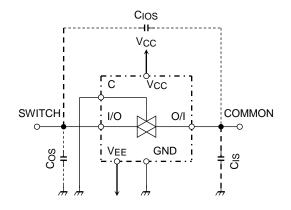
2. Cross Talk (control input-switch output) fIN = 1 MHz duty = 50% tr = tf = 6 ns



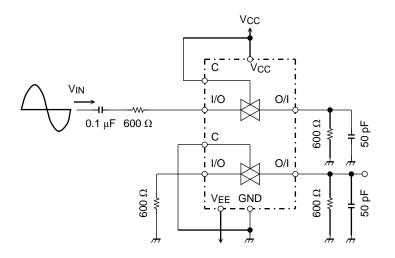
3. Feedthrough Attenuation



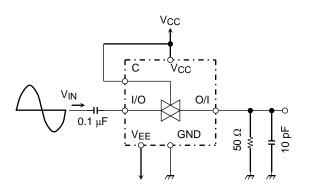
4. Clos, Cls, Cos



5. Cross Talk (between any two switches)



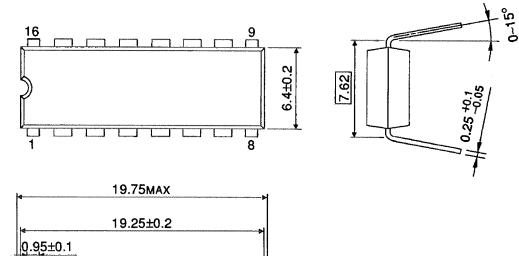
6. Frequency Response (switch on)

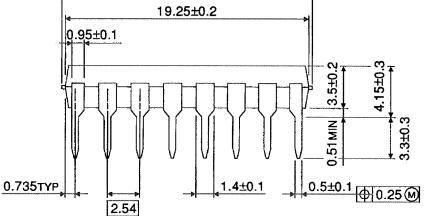


Package Dimensions

DIP16-P-300-2.54A

Unit : mm





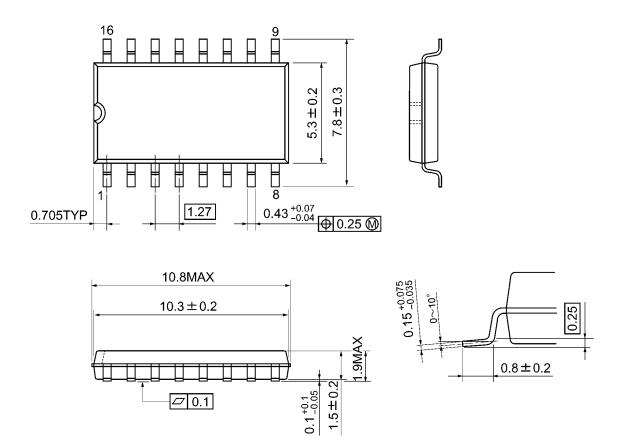
Weight: 1.00 g (typ.)



Package Dimensions

SOP16-P-300-1.27A

Unit: mm

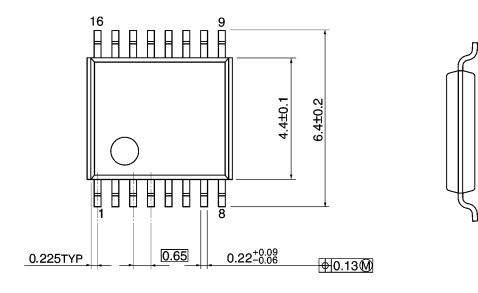


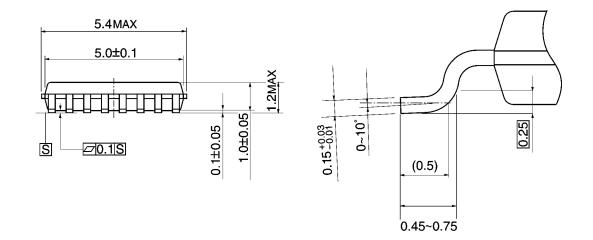
Weight: 0.18 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm





Weight: 0.06 g (typ.)

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